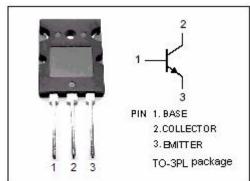


# isc Silicon NPN Power Transistor

## 2NC5566

#### **DESCRIPTION**

- High Current Capability
- · High Power Dissipation
- · High Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 230V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

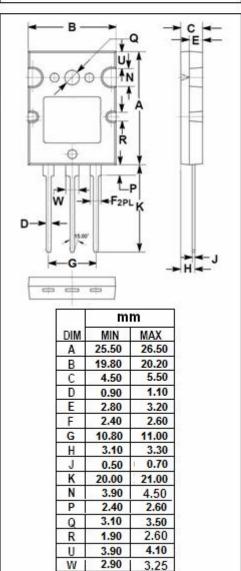


### **APPLICATIONS**

- · Power amplifier applications
- Recommend for 100W high fidelity audio frequency amplifier output stage applications

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	250	V
V <sub>CEO</sub>	Collector-Emitter Voltage	230	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	15	А
I <sub>B</sub>	Base Current-Continuous	1.5	Α
Pc	Collector Power Dissipation @ Tc=25℃	150	W
TJ	Junction Temperature	150	$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}\mathbb{C}$





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 30mA ; I <sub>B</sub> = 0	230			V			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8.0A; I <sub>B</sub> = 0.8A			2.5	V			
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 7A; V <sub>CE</sub> = 5V		1.0	1.5	V			
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 230V ; I <sub>E</sub> = 0			50	μ <b>А</b>			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			20	μ <b>А</b>			
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	55		160				
h <sub>FE-2</sub>	DC Current Gain	Ic= 7A; Vc= 5V	35						
Сов	Output Capacitance	I <sub>E</sub> =0 ; V <sub>CB</sub> = 10V;f= 1.0MHz		750		pF			
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> =1A; V <sub>CE</sub> = 5V		25		MHz			

### h<sub>FE-1</sub> Classifications

R	0	
55-110	80-160	

#### Notice:

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